



PBHV8115TLH

150 V, 1 A NPN high-voltage low V_{CEsat} transistor

9 February 2023

Product data sheet

1. General description

NPN high-voltage low V_{CEsat} transistor in a small SOT23 Surface-Mounted Device (SMD) plastic package.

PNP complement: PBHV9115TLH

2. Features and benefits

- High voltage
- Low collector-emitter saturation voltage V_{CEsat}
- High collector current capability I_C and I_{CM}
- Small SMD plastic package
- AEC-Q101 qualified

3. Applications

- Power management
- LCD backlighting
- LED driver for LED chain module
- Switch Mode Power Supply (SMPS)

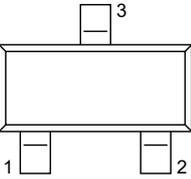
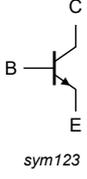
4. Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
V _{CEO}	collector-emitter voltage	open base	-	-	150	V
I _C	collector current		-	-	1	A
I _{CM}	peak collector current	single pulse; t _p ≤ 1 ms	-	-	2	A
h _{FE}	DC current gain	V _{CE} = 10 V; I _C = 50 mA; T _{amb} = 25 °C	70	-	300	

5. Pinning information

Table 2. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	B	base	 <p style="text-align: center;">SOT23</p>	 <p style="text-align: center;">sym123</p>
2	E	emitter		
3	C	collector		

6. Ordering information

Table 3. Ordering information

Type number	Package		
	Name	Description	Version
PBHV8115TLH	SOT23	plastic, surface-mounted package; 3 terminals; 1.9 mm pitch; 2.9 mm x 1.3 mm x 1 mm body	SOT23

7. Marking

Table 4. Marking codes

Type number	Marking code[1]
PBHV8115TLH	FB%

[1] % = placeholder for manufacturing site code

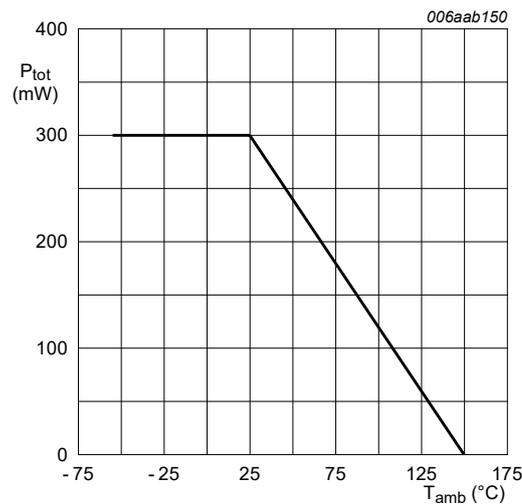
8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V_{CBO}	collector-base voltage	open emitter	-	400	V
V_{CEO}	collector-emitter voltage	open base	-	150	V
V_{CESM}	collector-emitter peak voltage	$V_{BE} = 0$ V	-	200	V
V_{EBO}	emitter-base voltage	open collector	-	6	V
I_C	collector current		-	1	A
I_{CM}	peak collector current	single pulse; $t_p \leq 1$ ms	-	2	A
I_{BM}	peak base current		-	400	mA
P_{tot}	total power dissipation	$T_{amb} \leq 25$ °C	[1]	300	mW
T_j	junction temperature		-	150	°C
T_{amb}	ambient temperature		-55	150	°C
T_{stg}	storage temperature		-65	150	°C

[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.



FR4 PCB, standard footprint

Fig. 1. Power derating curve

9. Thermal characteristics

Table 6. Thermal characteristics

Symbol	Parameter	Conditions		Min	Typ	Max	Unit
$R_{th(j-a)}$	thermal resistance from junction to ambient	in free air	[1]	-	-	417	K/W
$R_{th(j-sp)}$	thermal resistance from junction to solder point			-	-	70	K/W

[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

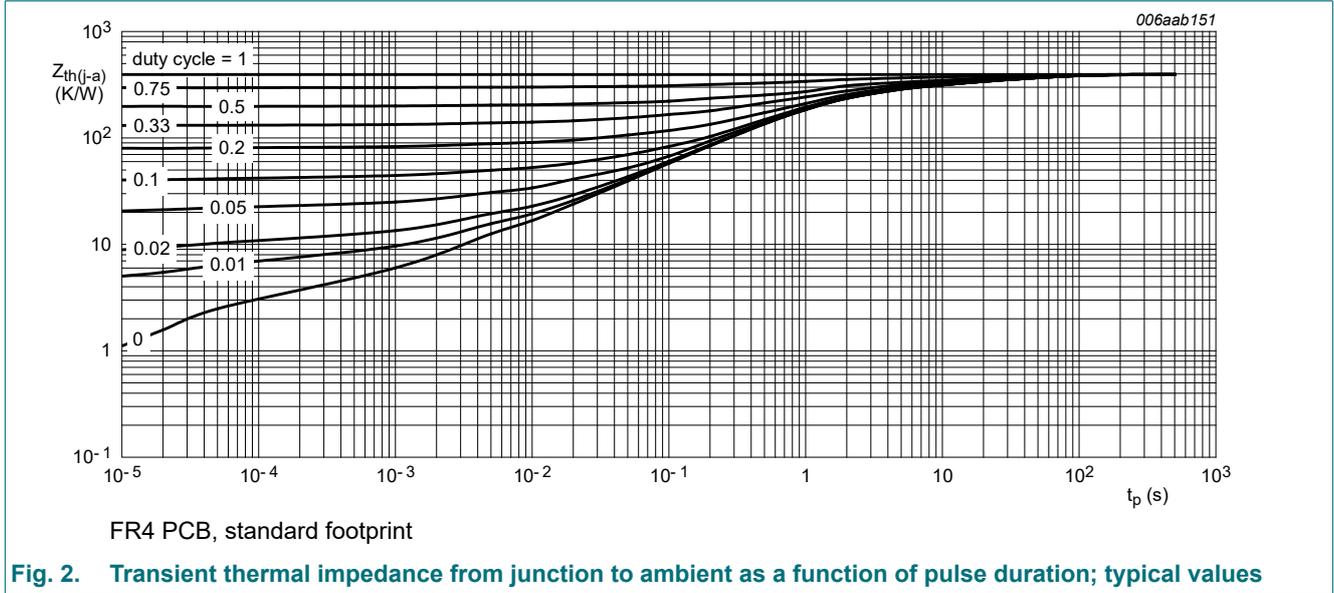
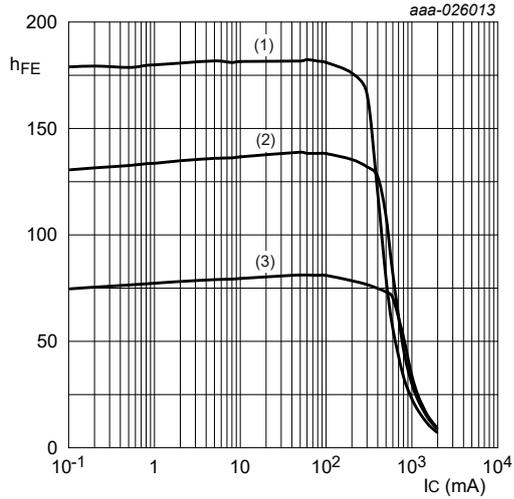


Fig. 2. Transient thermal impedance from junction to ambient as a function of pulse duration; typical values

10. Characteristics

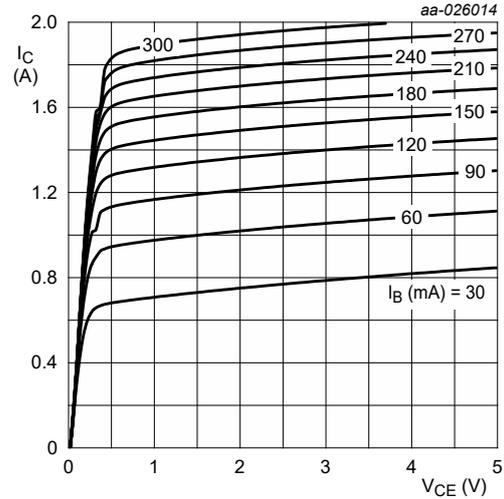
Table 7. Characteristics

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
I_{CBO}	collector-base cut-off current	$V_{CB} = 120\text{ V}; I_E = 0\text{ A}; T_{amb} = 25\text{ }^\circ\text{C}$	-	-	100	nA
		$V_{CB} = 120\text{ V}; I_E = 0\text{ A}; T_j = 150\text{ }^\circ\text{C}$	-	-	10	μA
I_{EBO}	emitter-base cut-off current	$V_{EB} = 4\text{ V}; I_C = 0\text{ A}; T_{amb} = 25\text{ }^\circ\text{C}$	-	-	100	nA
I_{CES}	collector-emitter cut-off current	$V_{CE} = 120\text{ V}; V_{BE} = 0\text{ V}; T_{amb} = 25\text{ }^\circ\text{C}$	-	-	100	nA
h_{FE}	DC current gain	$V_{CE} = 10\text{ V}; I_C = 50\text{ mA}; T_{amb} = 25\text{ }^\circ\text{C}$	70	-	300	
		$V_{CE} = 10\text{ V}; I_C = 100\text{ mA}; T_{amb} = 25\text{ }^\circ\text{C}$	60	-	300	
		$V_{CE} = 10\text{ V}; I_C = 500\text{ mA};$ pulsed; $t_p \leq 300\text{ }\mu\text{s}; \delta \leq 0.02; T_{amb} = 25\text{ }^\circ\text{C}$	50	-	300	
		$V_{CE} = 10\text{ V}; I_C = 1\text{ A};$ pulsed; $t_p \leq 300\text{ }\mu\text{s}; \delta \leq 0.02; T_{amb} = 25\text{ }^\circ\text{C}$	10	-	-	
V_{CEsat}	collector-emitter saturation voltage	$I_C = 100\text{ mA}; I_B = 10\text{ mA}; T_{amb} = 25\text{ }^\circ\text{C}$	-	-	60	mV
		$I_C = 100\text{ mA}; I_B = 20\text{ mA}; T_{amb} = 25\text{ }^\circ\text{C}$	-	-	50	mV
		$I_C = 1\text{ A}; I_B = 200\text{ mA};$ pulsed; $t_p \leq 300\text{ }\mu\text{s}; \delta \leq 0.02; T_{amb} = 25\text{ }^\circ\text{C}$	-	-	350	mV
V_{BEsat}	base-emitter saturation voltage		-	-	1.2	V
t_d	delay time	$V_{CC} = 6\text{ V}; I_C = 0.5\text{ A}; I_{B(on)} = 0.1\text{ mA};$ $I_{B(off)} = -0.1\text{ mA}; T_{amb} = 25\text{ }^\circ\text{C}$	-	10	-	ns
t_r	rise time		-	565	-	ns
t_{on}	turn-on time	$V_{CC} = 6\text{ V}; I_C = 0.5\text{ A}; I_{B(on)} = 0.1\text{ A};$ $I_{B(off)} = -0.1\text{ A}; T_{amb} = 25\text{ }^\circ\text{C}$	-	575	-	ns
t_s	storage time		-	1530	-	ns
t_f	fall time		-	700	-	ns
t_{off}	turn-off time		-	2230	-	ns
f_T	transition frequency	$V_{CE} = 10\text{ V}; I_C = 10\text{ mA}; f = 100\text{ MHz};$ $T_{amb} = 25\text{ }^\circ\text{C}$	-	30	-	MHz
C_c	collector capacitance	$V_{CB} = 20\text{ V}; I_E = 0\text{ A}; i_e = 0\text{ A}; f = 1\text{ MHz};$ $T_{amb} = 25\text{ }^\circ\text{C}$	-	6	-	pF
C_e	emitter capacitance	$V_{EB} = 0.5\text{ V}; I_C = 0\text{ A}; i_c = 0\text{ A};$ $f = 1\text{ MHz}; T_{amb} = 25\text{ }^\circ\text{C}$	-	150	-	pF



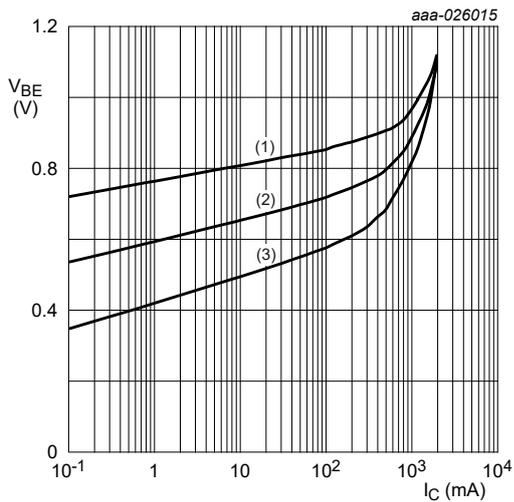
$V_{CE} = 10$ V
 (1) $T_{amb} = 100$ °C
 (2) $T_{amb} = 25$ °C
 (3) $T_{amb} = -55$ °C

Fig. 3. DC current gain as a function of collector current; typical values



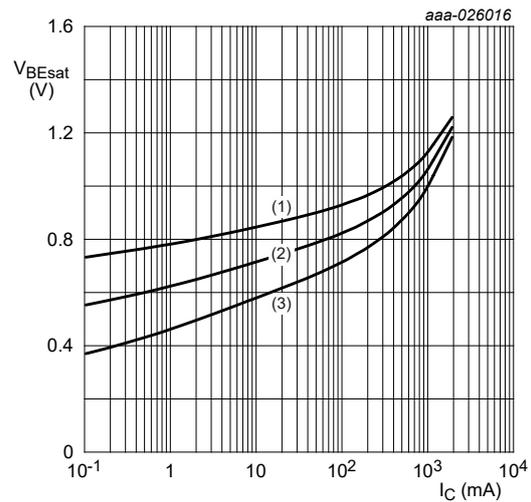
$T_{amb} = 25$ °C

Fig. 4. Collector current as a function of collector-emitter voltage; typical values



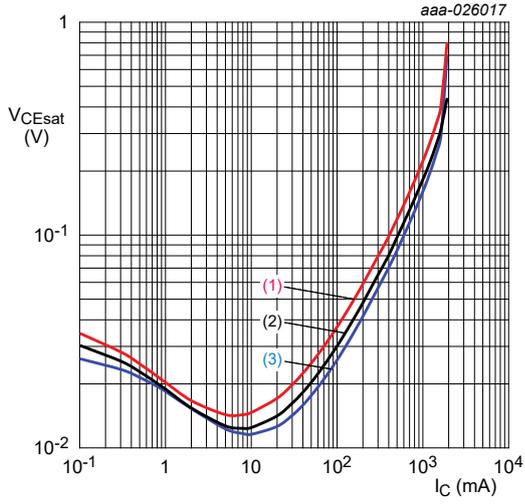
$V_{CE} = 10$ V
 (1) $T_{amb} = -55$ °C
 (2) $T_{amb} = 25$ °C
 (3) $T_{amb} = 100$ °C

Fig. 5. Base-emitter voltage as a function of collector current; typical values



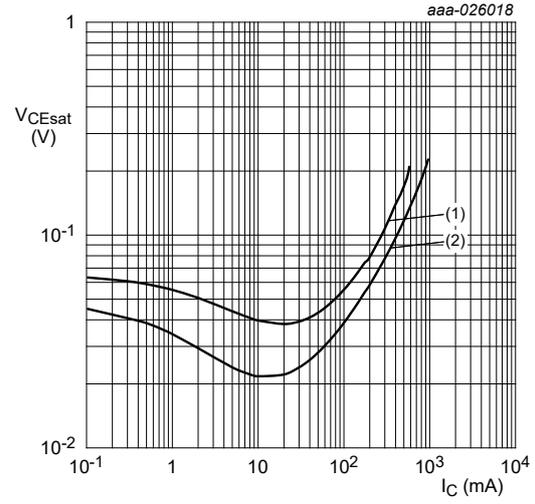
$I_C/I_B = 5$
 (1) $T_{amb} = -55$ °C
 (2) $T_{amb} = 25$ °C
 (3) $T_{amb} = 100$ °C

Fig. 6. Base-emitter saturation voltage as a function of collector current; typical values



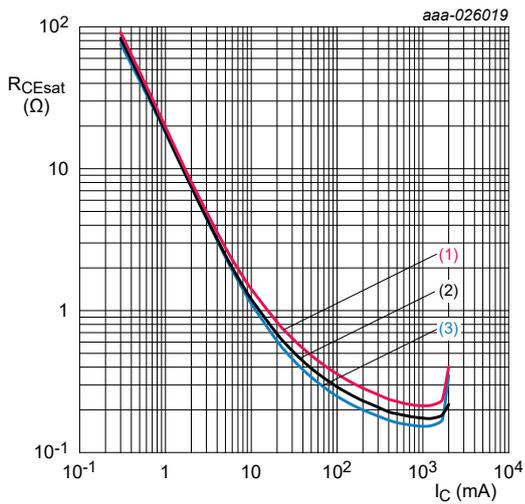
$I_C/I_B = 5$
 (1) $T_{amb} = 100\text{ °C}$
 (2) $T_{amb} = 25\text{ °C}$
 (3) $T_{amb} = -55\text{ °C}$

Fig. 7. Collector-emitter saturation voltage as a function of collector current; typical values



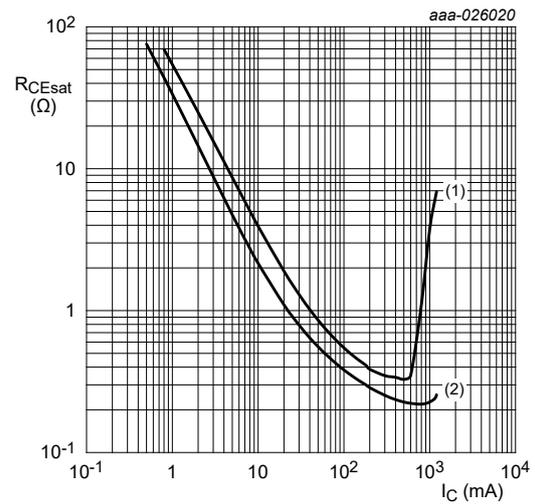
$T_{amb} = 25\text{ °C}$
 (1) $I_C/I_B = 20$
 (2) $I_C/I_B = 10$

Fig. 8. Collector-emitter saturation voltage as a function of collector current; typical values



$I_C/I_B = 5$
 (1) $T_{amb} = 100\text{ °C}$
 (2) $T_{amb} = 25\text{ °C}$
 (3) $T_{amb} = -55\text{ °C}$

Fig. 9. Collector-emitter saturation resistance as a function of collector current; typical values



$T_{amb} = 25\text{ °C}$
 (1) $I_C/I_B = 20$
 (2) $I_C/I_B = 10$

Fig. 10. Collector-emitter saturation resistance as a function of collector current; typical values

11. Test information

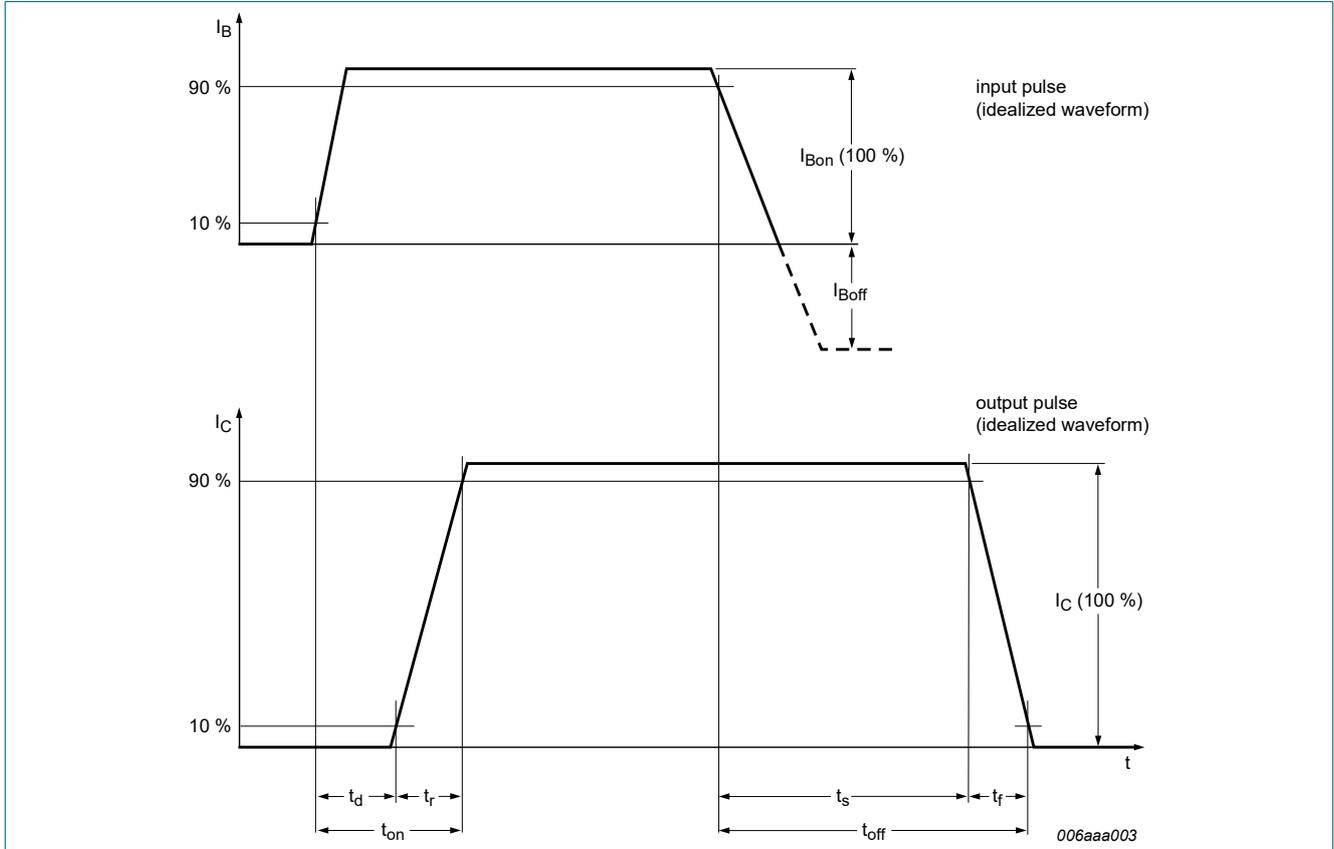


Fig. 11. Switching time definition

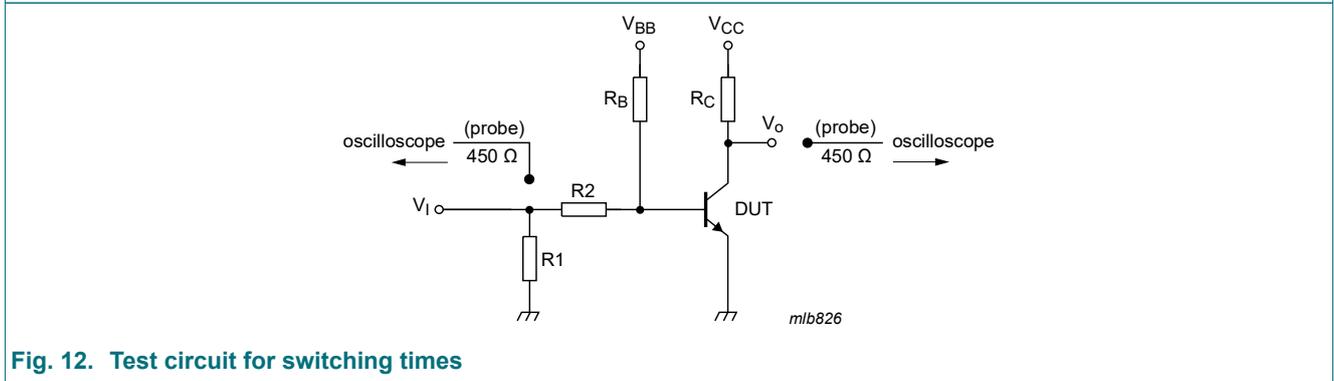
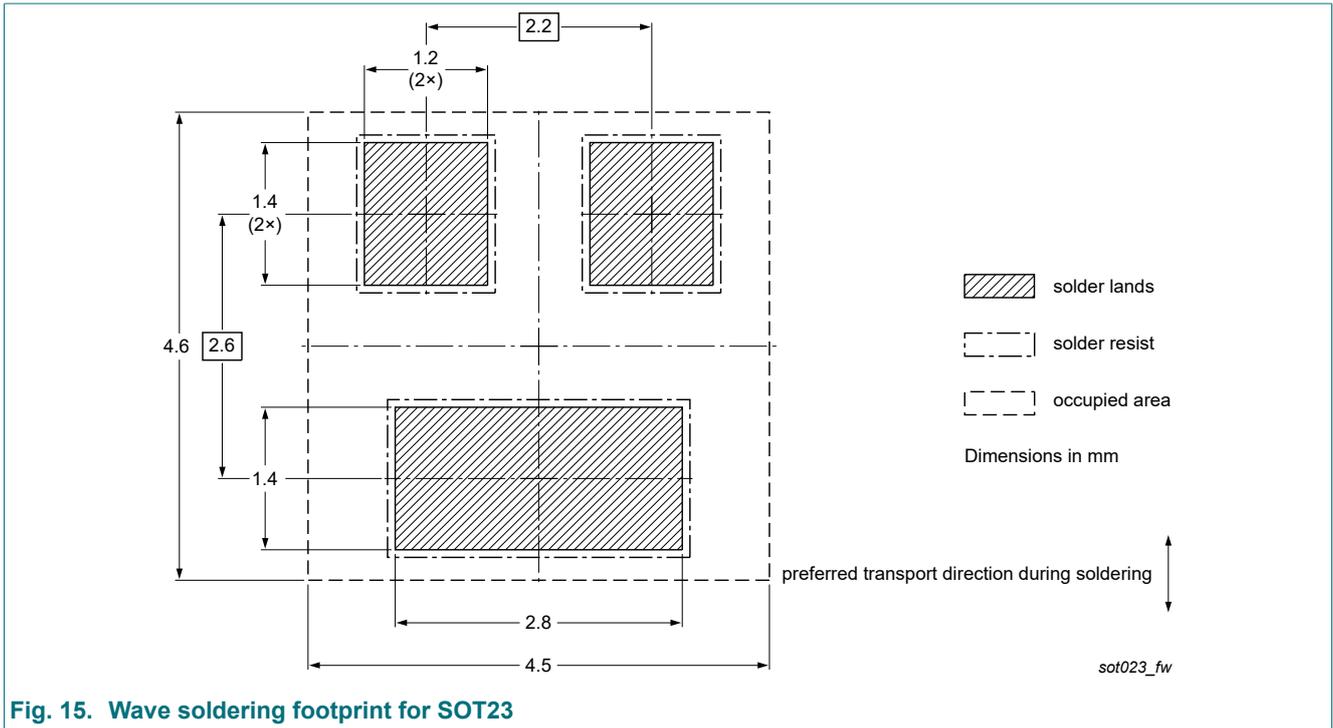


Fig. 12. Test circuit for switching times

Quality information

This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard Q101 - *Stress test qualification for discrete semiconductors*, and is suitable for use in automotive applications.



14. Revision history

Table 8. Revision history

Data sheet ID	Release date	Data sheet status	Change notice	Supersedes
PBHV8115TLH v.2	20230209	Product data sheet	-	PBHV8115TLH v.1
Modifications:	<ul style="list-style-type: none">The format of this data sheet has been redesigned to comply with the identity guidelines of Nexperia.Legal texts have been adapted to the new company name where appropriate.			
PBHV8115TLH v.1	2017010	Product data sheet	-	-

150 V, 1 A NPN high-voltage low VCEsat transistor

15. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions".
- [3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the internet at <https://www.nexperia.com>.

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Date of release: 9 February 2023